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# Journal of Crystal Growth

Volume 384, Pages 1-144 (1 December 2013)

## Editorial Board

Page IFC

Classical semiconductors

### ***Anomalous band bowing in pulsed laser deposited $Mg_xZn_{1-x}O$ films***

Original Research Article  
Pages 9-12  
Arpana Agrawal, Tanveer Ahmad Dar, D.M. Phase, Pratima Sen

### ***Numerical investigation of the influence of cooling flux on the generation of dislocations in cylindrical mono-like silicon growth***

Original Research Article  
Pages 13-20  
B. Gao, K. Kakimoto

### ***Chemical beam epitaxy growth and optimization of InAs/GaAs quantum dot multilayers***

Original Research Article  
Pages 21-26  
Jihene Zribi, Bouraoui Ilahi, Denis Morris, Vincent Aimez, Richard Arès

### ***Some physical effects of reaction rate on PbS thin films obtained by chemical bath deposition***

Original Research Article  
Pages 50-54  
Bariş Altıokka, Mevlana Celalettin Baykul, Mehmet Rıza Altıokka

### ***Growth of InAs quantum dots on Si-based GaAs nanowires by controlling the surface adatom diffusion***

Original Research Article  
Pages 82-87  
Xin Yan, Xia Zhang, Junshuai Li, Jiangong Cui, Qi Wang, Yongqing Huang, Xiaomin Ren

### ***Twinning in multicrystalline silicon for solar cells***

Original Research Article  
Pages 107-113  
G. Stokkan

### ***Numerical and experimental study of vacuum directional solidification purification process for SoG-Si in metallurgical***

**route**

Original Research Article  
Pages 122-128  
Tao Luo, Guoqiang Lv, Wenhui Ma, Kuixian Wei, Xi Yang, Shaoyuan Li

***Comparison of the spiral growth modes of silicon-face and carbon-face silicon carbide crystals***

Original Research Article  
Pages 129-134  
M. Seiss, T. Ouisse, D. Chaussende

Electronic materials

***Growth of TeO<sub>2</sub> single crystals by the low temperature gradient Czochralski method with nonuniform heating***

Original Research Article  
Pages 1-4  
A.E. Kokh, V.S. Shevchenko, V.A. Vlezko, K.A. Kokh

***Nitrogen-induced localized level observed by photoreflectance in GaAsN thin films grown by chemical beam epitaxy***

Original Research Article  
Pages 5-8  
Hidetoshi Suzuki, Akio Suzuki, Atsuhiko Fukuyama, Tetsuo Ikari

***The growth of In<sub>0.5</sub>Ga<sub>0.5</sub>N and InN layers on (1 1 1)Si using nanorod intermediate arrays***

Original Research Article  
Pages 55-60  
D. Cherns, R.F. Webster, S.V. Novikov, C.T. Foxon, A.M. Fischer, F.A. Ponce

***The MOVPE growth mechanism of catalyst-free self-organized GaN columns in H<sub>2</sub> and N<sub>2</sub> carrier gases***

Original Research Article  
Pages 61-65  
Xue Wang, Uwe Jahn, Johannes Ledig, Hergo-H. Wehmann, Martin Mandl, Martin Straßburg, Andreas Waag

***Epitaxial growth of highly compressively strained GeSn alloys up to 12.5% Sn***

Original Research Article  
Pages 71-76  
M. Oehme, D. Buca, K. Kosteki, S. Wirths, B. Holländer, E. Kasper, J. Schulze

***Microscopic study of germanium nanowires grown via gold-catalyzed chemical vapor deposition below the eutectic temperature***

Original Research Article  
Pages 77-81  
Marolop Simanullang, Koichi Usami, Tetsuo Kodera, Yukio Kawano, Shunri Oda

***Growth of CuO nanowires on graphene-deposited Cu foil by thermal oxidation method***

Original Research Article  
Pages 100-106  
Vu Xuan Hien, Se-Yun Kim, Joon-Hyung Lee, Jeong-Joo Kim, Young-Woo Heo

***Nucleation and phase formation during reactive magnetron co-sputtering of Cu(In,Ga)S<sub>2</sub> films, investigated by in situ EDXRD***

Original Research Article  
Pages 114-121  
Jonas Schulte, Stephan Brunken, Klaus Ellmer

Solution growth; industrial biological and molecular crystallization

***Synthesis of L-cystine nanotubes by alkalization of L-cysteine in the presence of gallium nitride***

Original Research Article  
Pages 33-38  
Gregorio Guadalupe Carbajal Arizaga

***Synthesis, growth, spectral, thermal and crystallographic studies of 5 $\alpha$ ,6 $\alpha$ -epoxycholestane single crystals***

Original Research Article  
Pages 135-143  
Shamsuzzaman, Hena Khanam, Ashraf Mashrai, Musheer Ahmad, Yahia Nasser Mabkhot, Wolfgang Frey, Nazish Siddiqui

General subjects

***Effect of Ba substitution in CsSrI<sub>3</sub>:Eu<sup>2+</sup>***

Original Research Article  
Pages 27-32  
H. Wei, M. Zhuravleva, K. Yang, B. Blalock, C.L. Melcher

***Optical floating zone crystal growth and magnetic properties of MgCr<sub>2</sub>O<sub>4</sub>***

Original Research Article  
Pages 39-43  
S.M. Koohpayeh, J.-J. Wen, M. Mourigal, S.E. Dutton, R.J. Cava, C.L. Broholm, T.M. McQueen

***Single-crystalline hafnium carbide nanowire growth below the eutectic temperature by CVD***

Original Research Article  
Pages 44-49  
Song Tian, Hejun Li, Yulei Zhang, Shouyang Zhang, Yongjie Wang, Jincui Ren, Xinfa Qiang

***Crystal growth of BaTi<sub>2</sub>O<sub>5</sub> by the floating zone method***

Original Research Article

Pages

66-70

Hirokazu Katsui, Keiji Shiga, Rong Tu, Takashi Goto

***High temperature solution growth and characterization of Cr<sub>2</sub>AlC single crystals***

Original

Research

Article

Pages

88-95

T. Ouisse, E. Sarigiannidou, O. Chaix-Pluchery, H. Roussel, B. Doisneau, D. Chaussende

***Effect of growth temperature on the impurity incorporation and material properties of N-polar GaN films grown by metal-organic chemical vapor deposition***

Original

Research

Article

Pages

96-99

Zhiyu Lin, Jincheng Zhang, Rongtao Cao, Wei Ha, Shuai Zhang, Xing Chen, Jingdong Yan, Shengrui Xu, Yi Zhao, Liang Li, Yue Hao